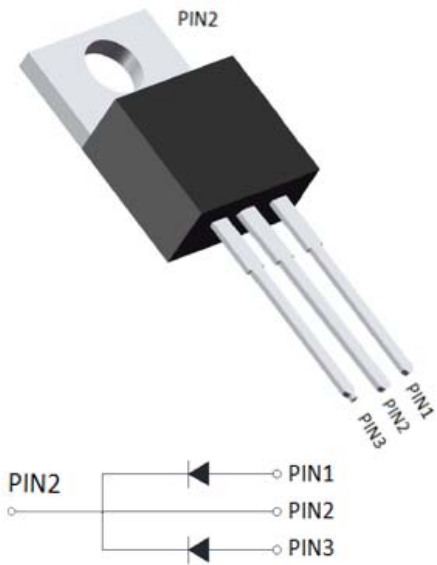


## Schottky Diodes



### Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

### Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### Mechanical Data

- **Package:** TO-220AB  
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR10200CTS
Device marking code			MBR10200CTS
Repetitive Peak Reverse Voltage	$V_{RRM}$	V	200
Average Rectified Output Current @60Hz sine wave, R-load, Ta=25°C	$I_o$	A	10
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, Ta=25°C	$I_{FSM}$	A	100
Current Squared Time @1ms≤t<8.3ms Tj=25°C,	$I^2t$	A <sup>2</sup> s	42
Storage Temperature	Tstg	°C	-55 ~ +175
Junction Temperature	Tj	°C	-55 ~ +175

### ■Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBR10200CTS
Maximum instantaneous forward voltage drop per diode	$V_{FM}$	V	$I_{FM}=5.0A$	0.95
Maximum DC reverse current at rated DC blocking voltage per diode	$I_{RRM1}$	mA	$V_{RM}=V_{RRM}$ Ta=25°C	0.1
	$I_{RRM2}$		$V_{RM}=V_{RRM}$ Ta=125°C	20

Note1:Pulse test:300uS pulse width,1% duty cycle

Note2:Pulse test:pulse width 40mS



# MBR10200CTS-B1-W5094HF

## ■ Thermal Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBR10200CTS
Thermal Resistance	Between junction and case	R <sub>θJ-C</sub>	°C/W	2.0

## ■ Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBR10200CTS	Approximate 1.9	50	1000	5000	Tube

## ■ Characteristics (Typical)

FIG1: I<sub>o</sub> -T<sub>c</sub> Curve

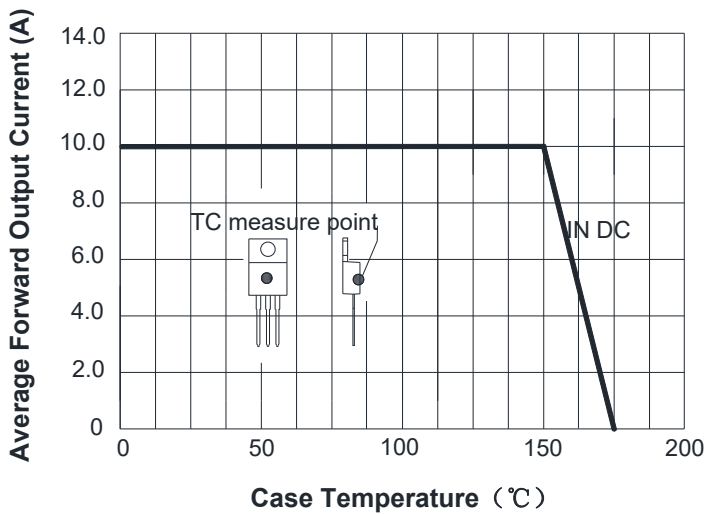


FIG2: Surge Forward Current Capability

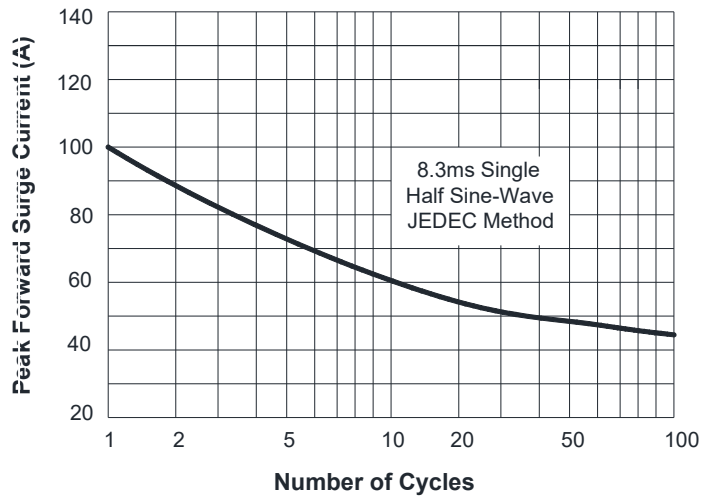


FIG3: Forward Voltage

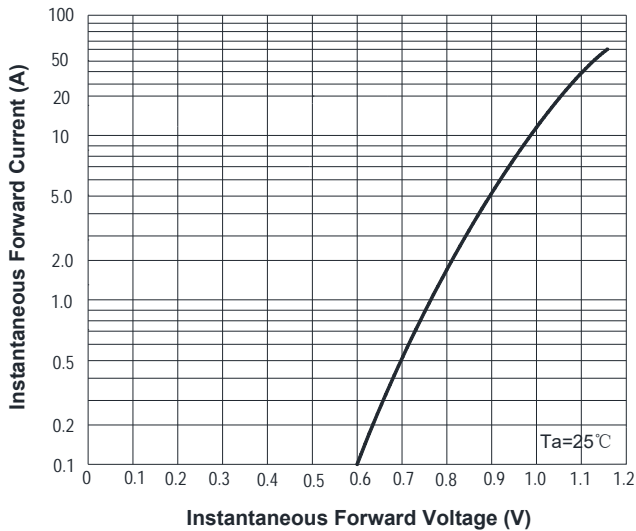
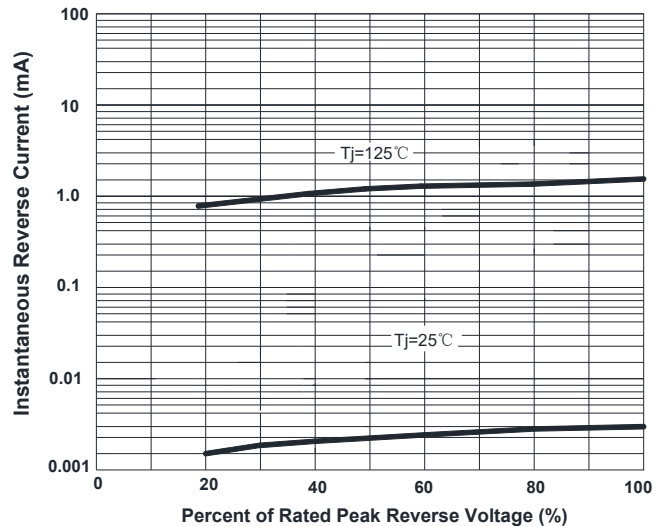


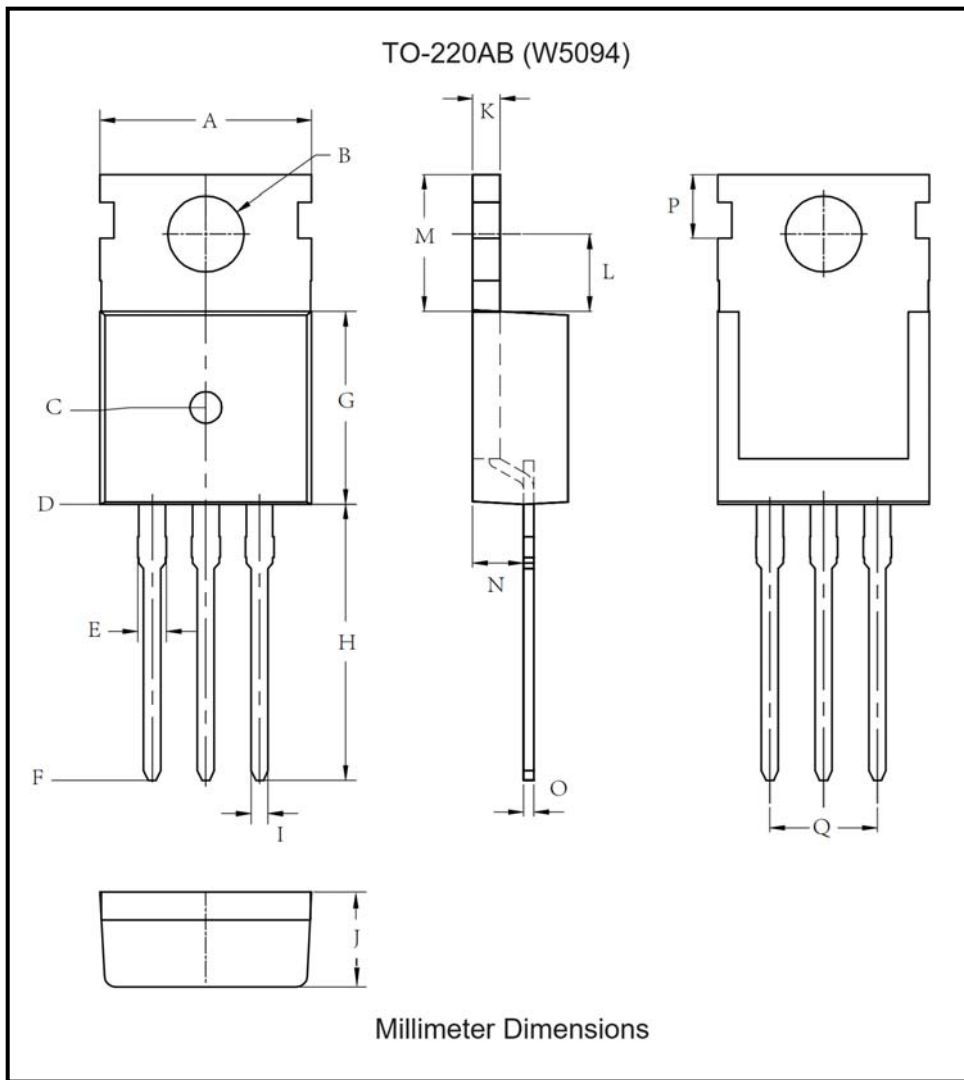
FIG.4: Instantaneous Reverse Characteristics





# MBR10200CTS-B1-W5094HF

## ■Outline Dimensions



TO-220AB		
Dim	Min	Max
A	9.9	10.1
B	TYP 3.6	
C	8.06	8.46
D	12.67	13.07
E	1.28	1.42
F	25.7	26.3
G	9	9.4
H	12.93	13.33
I	TYP 0.8	
J	4.3	4.7
K	1.285	1.315
L	3.47	3.87
M	6.27	6.67
N	2.2	2.6
O	0.485	0.515
P	2.8	3.2
Q	TYP 5.08	



## MBR10200CTS-B1-W5094HF

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